



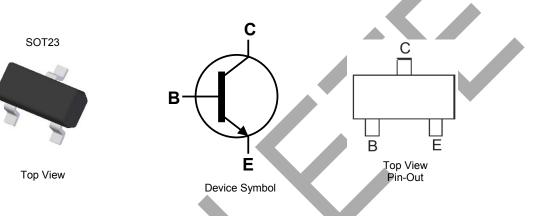
#### 25V NPN SMALL SIGNAL TRANSISTOR IN SOT23

### **Features**

- $BV_{CEO} > 25V$
- I<sub>C</sub> = 200mA High Collector Current
- Complementary PNP Type: MMBT4126
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23 •
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



## Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT4124-7-F	Standard	K1B	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

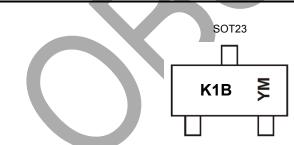
and Lead-free.

Notes:

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



K1N = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Kev

Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		Е	F		G	Н		I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	Ιc	200	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	310	mW	
	(Note 6)	FD	350		
Thermal Resistance, Junction to Ambient	(Note 5)	D	403	°C/W	
	(Note 6)	R <sub>0JA</sub>	357	0/11	
Thermal Resistance, Junction to Leads	(Note 7)	R <sub>θJL</sub>	350	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	С°		

### ESD Ratings (Note 8)

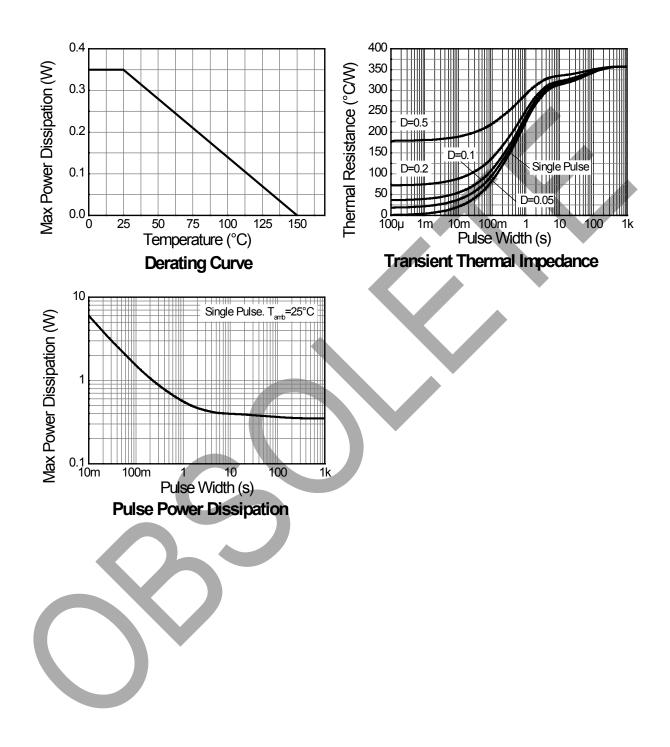
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 6. Same as Note 5, except the device is mounted on 15 mm x 15mm 1oz copper.

- Thermal resistance from junction to solder-point (at the end of the leads).
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





# **MMBT4124**

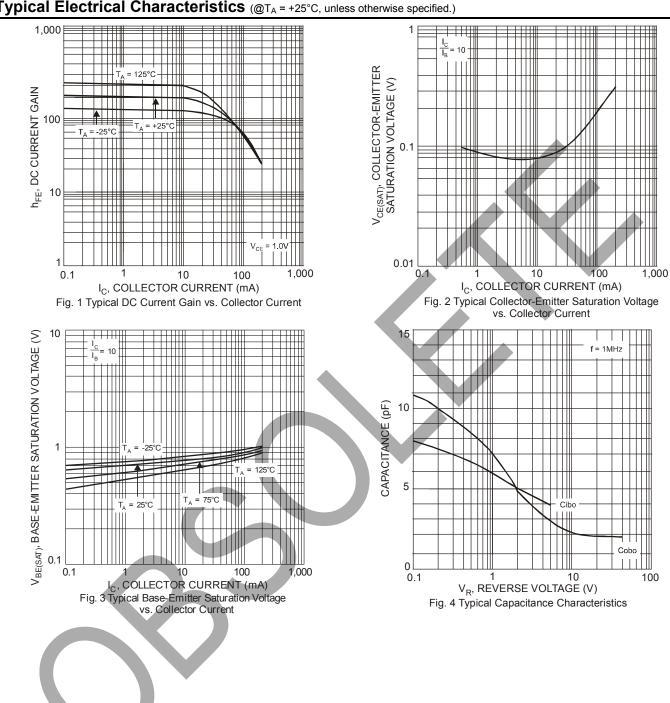
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	30	-	V	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	25	-	V	$I_{\rm C}$ = 1.0mA, $I_{\rm B}$ = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5.0	-	V	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$
Collector-Base Cut-off Current	I <sub>CBO</sub>	-	50	nA	$V_{CB}$ =20V, I <sub>E</sub> = 0
Emitter Base Cut-off Current	I <sub>EBO</sub>	-	50	nA	$V_{EB}$ =3.0V, $I_{C}$ = 0
ON CHARACTERISTICS (Note 9)					
DC Current Gain	h <sub>FF</sub>	120	360	_	$I_{\rm C} = 2mA, V_{\rm CE} = 1.0V$
	TIFE	60	-	-	$I_{\rm C} = 50 {\rm mA}, V_{\rm CE} = 1.0 {\rm V}$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	-	0.30	V	$I_{c} = 50 \text{mA}, I_{B} = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	-	0.95	V	$I_{\rm C}$ = 50mA, $I_{\rm B}$ = 5.0mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo	-	4.0	pF	$V_{CB} = 5.0V$ , f = 1.0MHz, $I_E = 0$
Input Capacitance	Cibo	-	8.0	pF	V <sub>EB</sub> = 0.5V, f = 1.0MHz, I <sub>C</sub> = 0
Small Signal Current Gain	h <sub>fe</sub>	120	480		$V_{CE} = 1.0V, I_{C} = 2.0mA,$
	··ie	0			f = 1.0kHz
Current Gain-Bandwidth Product	f⊤	300	_	MHz	$V_{CE} = 20V, I_{C} = 10mA,$
	.,	000		11112	f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

MMBT4124 Document number: DS30105 Rev. 14 - 4



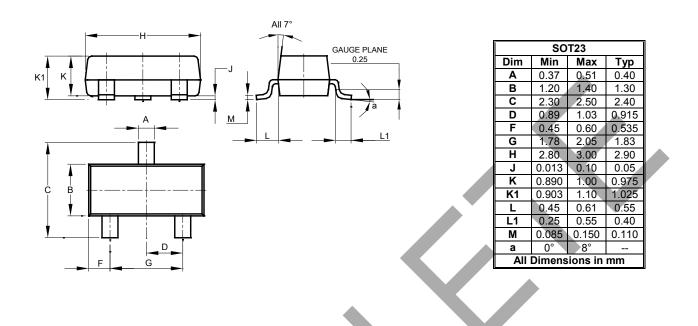


### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



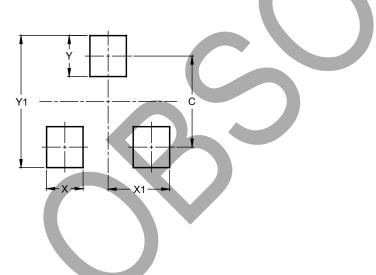
# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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